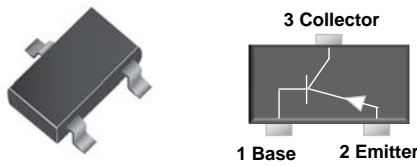
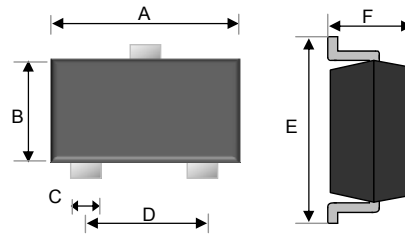


**Small Signal Transistor**
**SOT-23**

**Features**

- ✧ Epitaxial planar die construction
- ✧ Surface device type mounting
- ✧ Moisture sensitivity level 1
- ✧ Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- ✧ Pb free version and RoHS compliant
- ✧ Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

**Mechanical Data**

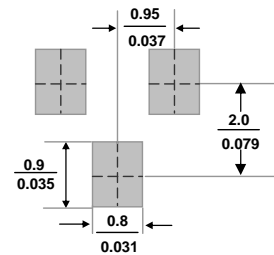
- ✧ Case : SOT- 23 small outline plastic package
- ✧ Terminal: Matte tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ High temperature soldering guaranteed: 260°C/10s
- ✧ Weight : 0.008gram (approximately)



Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	2.80	3.00	0.110	0.118
B	1.20	1.40	0.047	0.055
C	0.30	0.50	0.012	0.020
D	1.80	2.00	0.071	0.079
E	2.25	2.55	0.089	0.100
F	0.90	1.20	0.035	0.043

**Ordering Information**

Package	Part No.	Packing	Marking
SOT-23	BC856A RF	3K / 7" Reel	3A
SOT-23	BC856B RF	3K / 7" Reel	3B
SOT-23	BC857A RF	3K / 7" Reel	3E
SOT-23	BC857B RF	3K / 7" Reel	3F
SOT-23	BC857C RF	3K / 7" Reel	3G
SOT-23	BC858A RF	3K / 7" Reel	3J
SOT-23	BC858B RF	3K / 7" Reel	3K
SOT-23	BC858C RF	3K / 7" Reel	3L
SOT-23	BC856A RFG	3K / 7" Reel	3A
SOT-23	BC856B RFG	3K / 7" Reel	3B
SOT-23	BC857A RFG	3K / 7" Reel	3E
SOT-23	BC857B RFG	3K / 7" Reel	3F
SOT-23	BC857C RFG	3K / 7" Reel	3G
SOT-23	BC858A RFG	3K / 7" Reel	3J
SOT-23	BC858B RFG	3K / 7" Reel	3K
SOT-23	BC858C RFG	3K / 7" Reel	3L

**Suggested PAD Layout**

**Maximum Ratings and Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified.

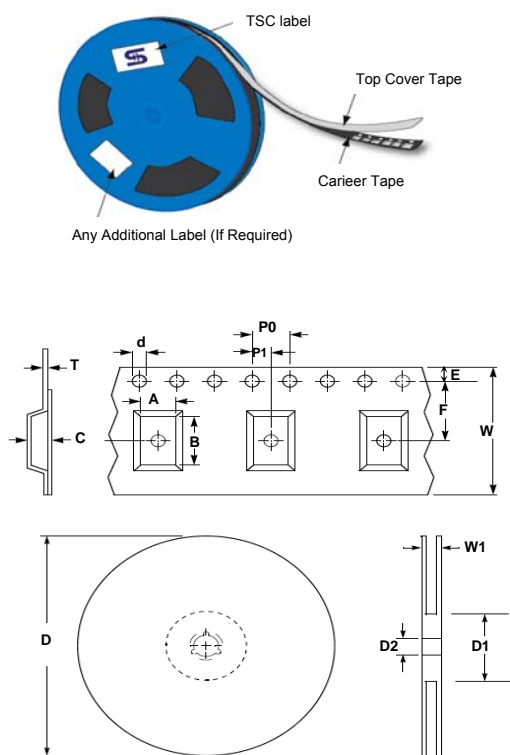
**Maximum Ratings**

Type Number	Symbol	Value	Units
Power Dissipation	$P_D$	250	mW
Collector-Base Voltage	$V_{CBO}$	BC856	-80
		BC857	-50
		BC858	-30
Collector-Emitter Voltage	$V_{CEO}$	BC856	-65
		BC857	-45
		BC858	-30
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-0.1	A
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to + 150	°C

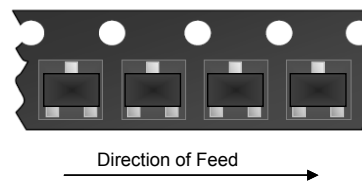
Notes:1. Valid provided that electrodes are kept at ambient temperature

**Small Signal Transistor**
**Electrical Characteristics**

Type Number	Symbol	Min	Max	Units
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-80 -50 -30	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-65 -45 -30	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	-	V
Collector Cut-off Current	$I_{CBO}$	-	-15	nA
Emitter Cut-off Current	$I_{EBO}$	-	-0.1	$\mu$ A
DC current gain	$h_{FE}$	125 220 420	250 475 800	
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	-0.65	V
Base-Emitter saturation voltage	$V_{BE(sat)}$	-	-1.1	V
Transition frequency	$f_T$	100	-	MHz

**Tape & Reel specification**


Item	Symbol	Dimension(mm)
Carrier width	A	3.15 ±0.10
Carrier length	B	2.77 ±0.10
Carrier depth	C	1.22 ±0.10
Sprocket hole	d	1.50 ± 0.10
Reel outside diameter	D	178 ± 1
Reel inner diameter	D1	55 Min
Feed hole width	D2	13.0 ± 0.20
Sprocket hole position	E	1.75 ±0.10
Punch hole position	F	3.50 ±0.05
Sprocket hole pitch	P0	4.00 ±0.10
Embossment center	P1	2.00 ±0.05
Overall tape thickness	T	0.229 ±0.013
Tape width	W	8.10 ±0.20
Reel width	W1	12.30 ±0.20



**Small Signal Transistor**

**Rating and Characteristic Curves**

Figure 1. Static Characteristic

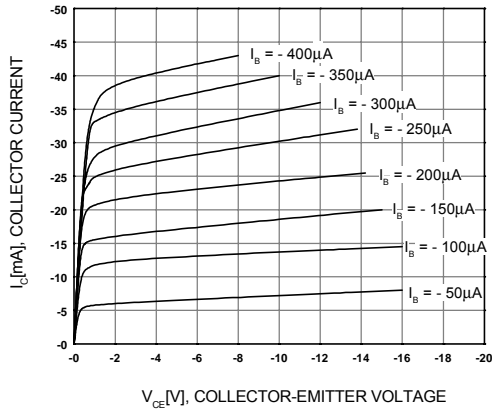


Figure 2. DC Current Gain

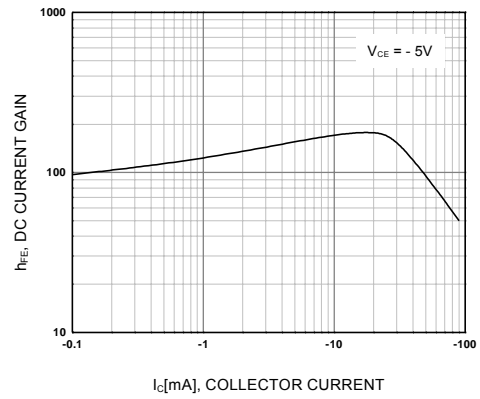


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation

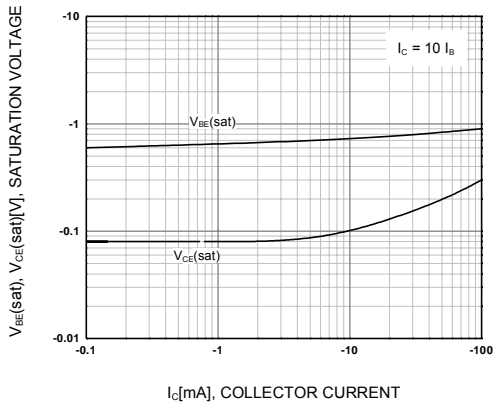


Figure 4. Base-Emitter On Voltage

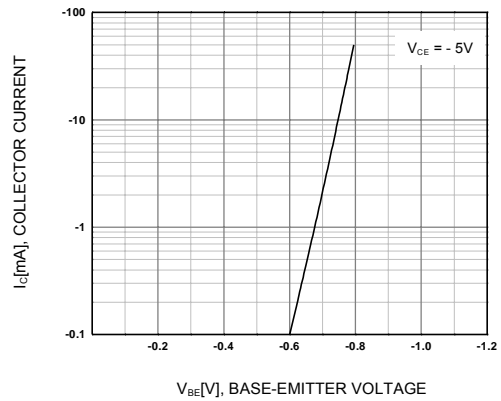


Figure 5. Collector Output Capacitance

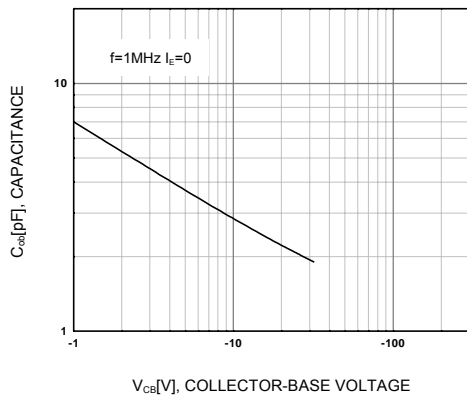
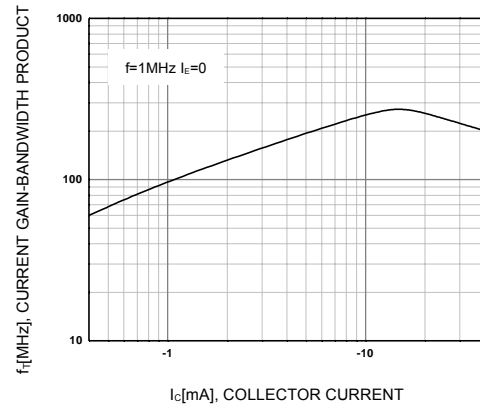


Figure 6. Current Gain Bandwidth Product



**Small Signal Transistor**

**Rating and Characteristic Curves**

Figure 7. DC current gain as a function of collector current; typical values

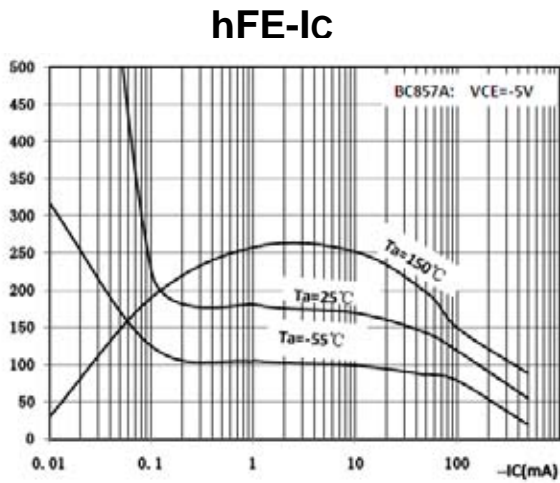


Figure 8. Base-emitter voltage as a function of collector current; typical values

